







SN54HCT240, SN74HCT240

SCLS174H - MARCH 1984 - REVISED AUGUST 2024

## **SNx4HCT240 Octal Buffers and Line Drivers With 3-State Outputs**

#### 1 Features

- Operating voltage range of 4.5V to 5.5V
- High-current outputs drive up to 15 LSTTL loads
- Low power consumption, 80µA max I<sub>CC</sub>
- Typical  $t_{pd}$  = 12 ns
- ±6mA output drive at 5V
- Low input current of 1µA max
- Inputs are TTL-voltage compatible
- 3-state outputs drive bus lines or buffer memory address registers

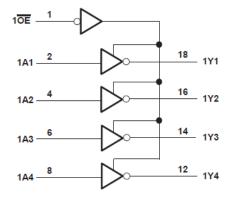
### 2 Description

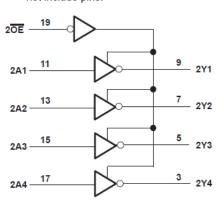
These octal buffers and line drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. The 'HCT240 devices are organized as two 4-bit buffers/drivers with separate output-enable (OE) inputs. When  $\overline{OE}$  is low, the device passes inverted data from the A inputs to the Y outputs. When  $\overline{OE}$  is high, the outputs are in the high-impedance state.

#### **Device Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE(2)	BODY SIZE(3)
SN74HCT240	DGS (VSSOP, 20)	5.1mm × 4.9mm	5.1mm × 3mm
	DW (SOIC, 20)	12.80mm x 10.3mm	12.80mm x 7.50mm
	PDIP (20)	24.33mm × 9.4mm	24.33mm × 6.35mm
	NS (SOP, 20)	12.6mm x 7.8mm	12.6mm x 5.3mm
	PW (TSSOP, 20)	6.50mm x 6.4mm	6.50mm x 4.40mm
SN54HCT240	J (CDIP, 20)	24.2mm x 7.62mm	24.2 mm x 6.92mm
	FK (LCCC, 20)	8.9mm x 8.9mm	8.9mm x 8.9mm

- For more information, see Mechanical, Packaging, and (1) Orderable Information.
- The package size (length × width) is a nominal value and includes pins, where applicable.
- The body size (length × width) is a nominal value and does not include pins.





**Functional Block Diagram** 

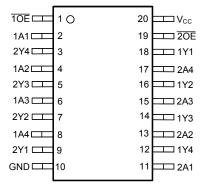


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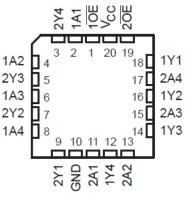
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## 3 Pin Configuration and Functions



J, DGS, DW, N, NS, or PW package 20-Pin CDIP, SOIC, PDIP, NS, or TSSOP Top View



FK Package 20-Pin LCCC Top View

NAME <sup>(1)</sup>	PIN	TYPE	DESCRIPTION
10E	1	I	Output enable 1
1A1	2	I	1A1 input
2Y4	3	0	2Y4 output
1A2	4	I	1A2 input
2Y3	5	0	2Y3 output
1A3	6	I	1A3 input
2Y2	7	0	2Y2 output
1A4	8	I	1A4 input
2Y1	9	0	2Y1 output
GND	10	_	Ground pin
2A1	11	1	2A1 input
1Y4	12	0	1Y4 output
2A2	13	I	2A2 input
1Y3	14	0	1Y3 output
2A3	15	I	2A3 input
1Y2	16	0	1Y2 output
2A4	17	1	2A4 input
1Y1	18	0	1Y1 output
2OE	19	1	Output enable 2
VCC	20	_	Power pin

(1) I = input, O = output, P = power, FB = feedback, GND = ground, N/A = not applicable



## 4 Specifications

### 4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

·	3 1 3 (	,	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	7	V
I <sub>IK</sub>	Input clamp current <sup>(2)</sup>	$V_I < 0$ or $V_I > V_{CC}$		±20	mA
I <sub>OK</sub>	Output clamp current <sup>(2)</sup>	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	V <sub>O</sub> = 0 to V <sub>CC</sub>		±35	mA
	Continuous current through V <sub>CC</sub> or GND			±70	mA
TJ	Junction temperature			150	°C
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 4.2 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			SN	54HCT240		SN	74HCT240		UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNII
V <sub>CC</sub>	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2			2			V
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V			0.8	-		0.8	V
VI	Input voltage		0		V <sub>CC</sub>	0		V <sub>CC</sub>	V
Vo	Output voltage		0		V <sub>CC</sub>	0		V <sub>CC</sub>	V
Δt/Δν	Input transition rise/fall time	•			500			500	ns
T <sub>A</sub>	Operating free-air temperat	ure	-55		125	-40		85	°C

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

#### 4.3 Thermal Information

		DGS (VSSOP)	DW (SOIC)	N (PDIP)	NS (SOP)	PW (TSSOP)	
THERMAL	. METRIC	20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance <sup>(1)</sup>	130.6	109.1	84.6	113.4	131.8	°C/W
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	68.7	76	72.5	78.6	72.2	°C/W
R <sub>0JB</sub>	Junction-to-board thermal resistance	85.4	77.6	65.3	78.4	82.8	°C/W
ΨЈТ	Junction-to-top characterization parameter	10.5	51.5	55.3	47.1	21.5	°C/W
ΨЈВ	Junction-to-board characterization parameter	85.0	77.1	65.2	78.1	82.4	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	N/A	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

Product Folder Links: SN54HCT240 SN74HCT240

<sup>(2)</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



#### 4.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CO	NDITIONS	V <sub>cc</sub>	T,	<sub>A</sub> = 25°C		SN54HC	T240	SN74HC	T240	UNIT
PANAMILILIX	1231 00	NDITIONS	▼CC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONIT
V <sub>OH</sub>		I <sub>OH</sub> = -20 μA	4.5 V	4.4	4.499		4.4		4.4		V
∨он	VI - VIH OI VIL	I <sub>OH</sub> = −6 mA	4.5 V	3.98	4.3		3.7		3.84		V
V <sub>OL</sub>	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 20 μA	4.5 V		0.001	0.1		0.1		0.1	V
VOL	AOF AIH OLAIF	I <sub>OL</sub> = 6 mA	4.5 V		0.17	0.26		0.4		0.33	V
I <sub>1</sub>	$V_I = V_{CC}$ or 0		5.5 V	,	±0.1	±100		±1000		±1000	nA
I <sub>OZ</sub>	$V_O = V_{CC}$ or 0,	$V_I = V_{IH}$ or $V_{IL}$	5.5 V	,	±0.01	±0.5		±10		±5	μA
I <sub>CC</sub>	$V_I = V_{CC}$ or 0,	I <sub>O</sub> = 0	5.5 V	,		8		160		80	μΑ
ΔI <sub>CC</sub> <sup>(1)</sup>	One input at 0.5 Other inputs at		5.5 V		1.4	2.4		3		2.9	mA
C <sub>i</sub>			4.5 V to 5.5 V		3	10		10		10	pF

<sup>(1)</sup> This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or V<sub>CC</sub>.

## 4.5 Switching Characteristics

over recommended operating free-air temperature range, C<sub>I</sub> = 50 pF (unless otherwise noted) (see Figure 5-1)

PARAMETER	FROM	то	V <sub>cc</sub>	TA	= 25°C		SN54HCT240		SN74HCT240		UNIT	
PARAMETER	(INPUT)	(OUTPUT)	<b>V</b> CC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	Oldii	
+	Α	V	4.5 V		13	25		37		32	ns	
$t_{pd}$	A	I	5.5 V		12	23		33		29	115	
+	ŌĒ	Y	4.5 V		21	35		53		44	ns	
t <sub>en</sub>	OE	Ī	5.5 V		19	32		48		40	115	
<b>4</b>	ŌĒ	V	4.5 V		19	35		53		44	ns	
t <sub>dis</sub>	OL	I	5.5 V		18	32		48		40	115	
	Y	4.5 V		8	12		18		15	no		
t <sub>t</sub>		Ţ	5.5 V		7	11		16		14	ns	

## 4.6 Switching Characteristics

over recommended operating free-air temperature range,  $C_L = 150 \text{ pF}$  (unless otherwise noted) (see Figure 5-1)

PARAMETER FROM		то	V <sub>cc</sub>	T	= 25°C		SN54HC	T240	SN74HC	T240	UNIT
PARAMETER	(INPUT)	(OUTPUT)	▼CC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONII
<b>+</b> .	Α	V	4.5 V		20	42		63		53	ns
t <sub>pd</sub>	A	Ţ	5.5 V		19	38		56		48	115
+	ŌĒ	V	4.5 V		25	52		79		65	ns
t <sub>en</sub>	OL	Y	5.5 V		22	47		71		59	115
t		V	4.5 V		17	42		63		53	ns
Ч			5.5 V		14	38		57		48	115

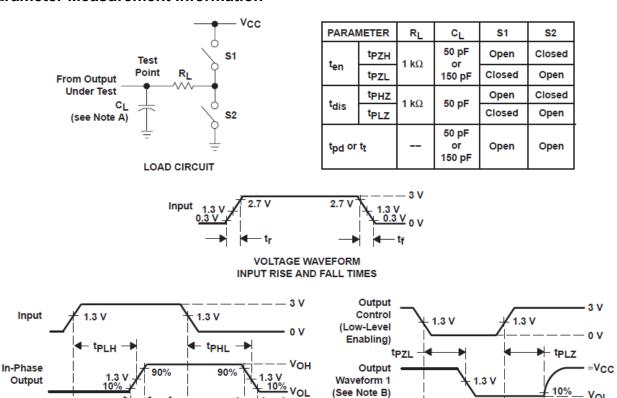
## 4.7 Operating Characteristics

T<sub>A</sub> = 25°C

	PARAMETER	TESTCONDITIONS	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance	No load	40	pF



#### **5 Parameter Measurement Information**



- VOLTAGE WAVEFORMS
  PROPAGATION DELAY AND OUTPUT RISE AND FALL TIMES
- VOLTAGE WAVEFORMS
  ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS

1.3 V

90%

≃0 V

tp7H

Output

Waveform 2

(See Note B)

A. C<sub>L</sub> includes probe and test-fixture capacitance.

**tPHL** 

90%

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O$  = 50  $\Omega$ ,  $t_r$  = 6 ns,  $t_f$  = 6 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.

Out-of-

Phase

Output

- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

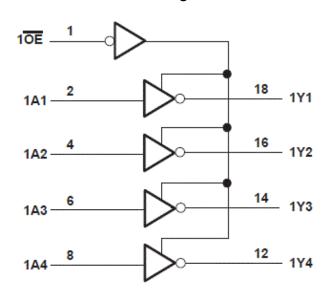
Figure 5-1. Load Circuit and Voltage Waveforms

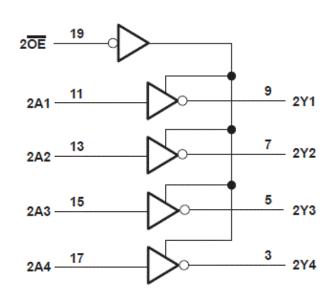
## **6 Detailed Description**

#### 6.1 Overview

These octal buffers and line drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. The 'HCT240 devices are organized as two 4-bit buffers/drivers with separate output-enable ( $\overline{OE}$ ) inputs. When  $\overline{OE}$  is low, the device passes inverted data from the A inputs to the Y outputs. When  $\overline{OE}$  is high, the outputs are in the high-impedance state.

#### 6.2 Functional Block Diagram





#### 6.3 Device Functional Modes

Table 6-1. Function Table (Each Buffer/Driver)

INP	INPUTS					
ŌĒ	Α	Y				
L	Н	L				
L	L	Н				
Н	Х	Z				



## 7 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

## 7.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A  $0.1\mu F$  capacitor is recommended for this device. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. The  $0.1\mu F$  and  $1\mu F$  capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

#### 7.2 Layout

#### 7.2.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices, inputs must never be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V<sub>CC</sub>, whichever makes more sense for the logic function or is more convenient.

Product Folder Links: SN54HCT240 SN74HCT240

## 8 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

#### 8.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 8.2 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 8.3 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

#### 8.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 8.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

#### 9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

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## 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

2-Dec-2024 www.ti.com

### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
85505012A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	85505012A SNJ54HCT 240FK	Samples
8550501RA	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8550501RA SNJ54HCT240J	Samples
JM38510/65753BRA	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 65753BRA	Samples
M38510/65753BRA	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 65753BRA	Samples
SN54HCT240J	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	SN54HCT240J	Samples
SN74HCT240DGSR	ACTIVE	VSSOP	DGS	20	5000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HT240	Samples
SN74HCT240DW	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	-40 to 85	HCT240	
SN74HCT240DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT240	Samples
SN74HCT240DWRE4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT240	Samples
SN74HCT240N	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74HCT240N	Samples
SN74HCT240NSR	ACTIVE	SOP	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT240	Samples
SN74HCT240PW	OBSOLETE	TSSOP	PW	20		TBD	Call TI	Call TI	-40 to 85	HT240	
SN74HCT240PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT240	Samples
SN74HCT240PWT	OBSOLETE	TSSOP	PW	20		TBD	Call TI	Call TI	-40 to 85	HT240	
SNJ54HCT240FK	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	85505012A SNJ54HCT 240FK	Samples
SNJ54HCT240J	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8550501RA SNJ54HCT240J	Samples

<sup>(1)</sup> The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

## PACKAGE OPTION ADDENDUM

www.ti.com 2-Dec-2024

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN54HCT240, SN74HCT240:

Catalog: SN74HCT240

Military: SN54HCT240

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

**PACKAGE MATERIALS INFORMATION** 

www.ti.com 7-Dec-2024

### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HCT240DGSR	VSSOP	DGS	20	5000	330.0	16.4	5.4	5.4	1.45	8.0	16.0	Q1
SN74HCT240DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74HCT240DWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74HCT240NSR	SOP	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74HCT240NSR	SOP	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74HCT240PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74HCT240PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1



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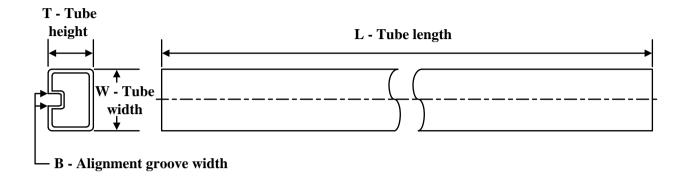
### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HCT240DGSR	VSSOP	DGS	20	5000	353.0	353.0	32.0
SN74HCT240DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74HCT240DWR	SOIC	DW	20	2000	356.0	356.0	41.0
SN74HCT240NSR	SOP	NS	20	2000	367.0	367.0	45.0
SN74HCT240NSR	SOP	NS	20	2000	367.0	367.0	45.0
SN74HCT240PWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74HCT240PWR	TSSOP	PW	20	2000	356.0	356.0	35.0

## **PACKAGE MATERIALS INFORMATION**

www.ti.com 7-Dec-2024

### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
85505012A	FK	LCCC	20	55	506.98	12.06	2030	NA
SN74HCT240N	N	PDIP	20	20	506	13.97	11230	4.32
SNJ54HCT240FK	FK	LCCC	20	55	506.98	12.06	2030	NA

## **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

### PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



## 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



## N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



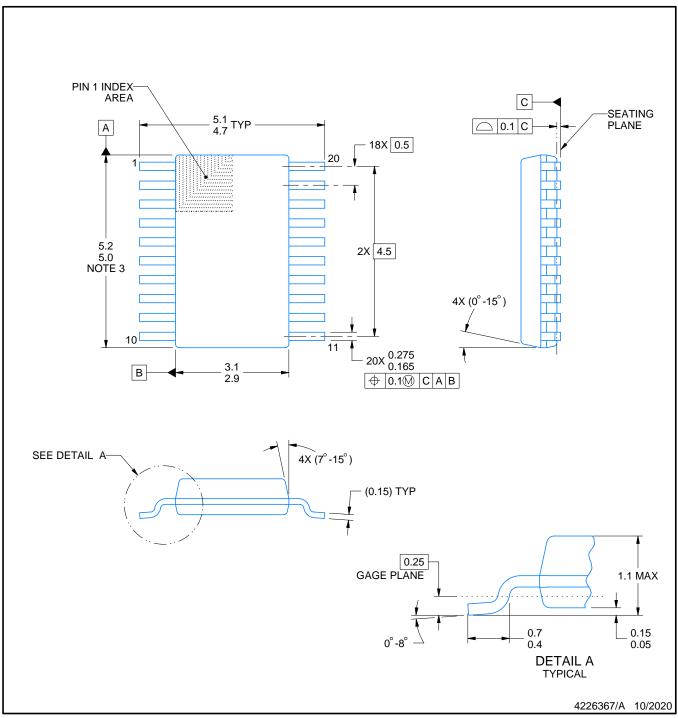


NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







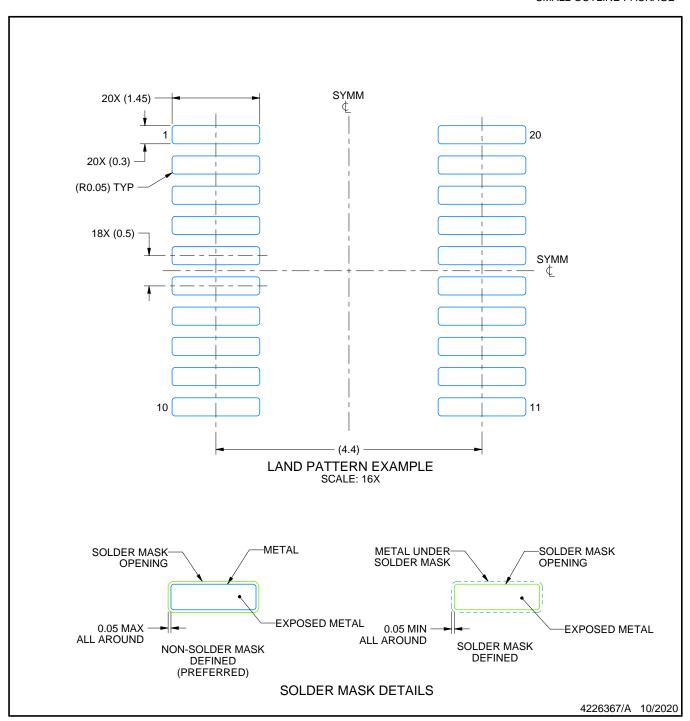
PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. No JEDEC registration as of September 2020.
- 5. Features may differ or may not be present.

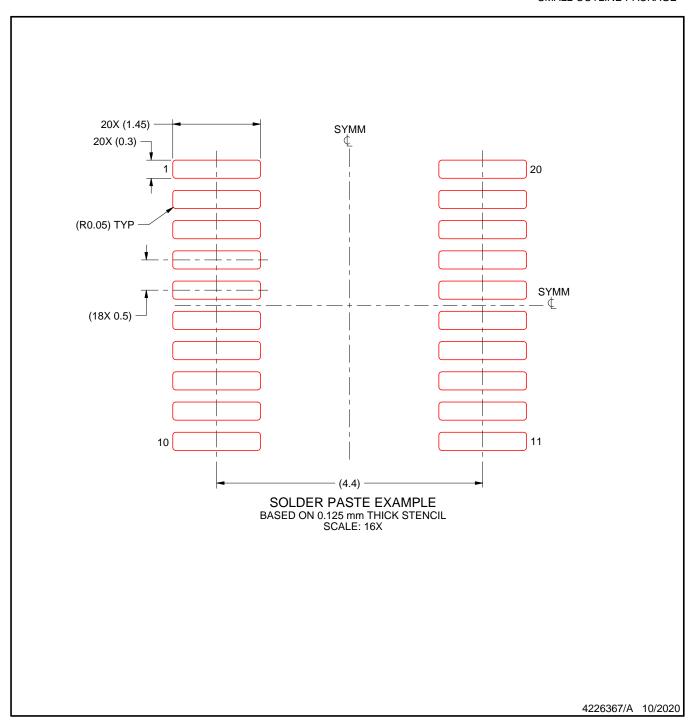




#### NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
- 9. Size of metal pad may vary due to creepage requirement.
- Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.





NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.



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